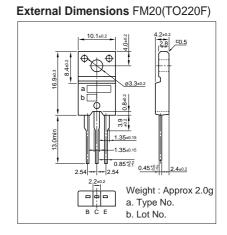
## 2SC389

Silicon NPN Triple Diffused Planar Transistor (High Voltage and High Speed Switchihg Transistor)

Application: Switching Regulator and General Purpose

Absolute maximum ratings (Ta=25°C)							
Symbol	2SC3890	Unit					
Vсво	500	V					
VCEO	400	V					
VEBO	10	V					
Ic	7(Pulse14)	А					
lB	2	А					
Pc	30(Tc=25°C)	W					
Tj	150	°C					
Tstg	-55 to +150	°C					

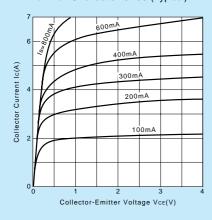
Electrical Cl	haracteristics	(Ta=25°C)		
Symbol	Conditions	2SC3890	Unit	
Ісво	Vcb=500V	100max	μΑ	
ІЕВО	VEB=10V	100max	μΑ	
V(BR)CEO	Ic=25mA	400min	V	
hfe	Vce=4V, Ic=3A	10 to 30		
Vce(sat)	Ic=3A, IB=0.6A	0.5max	V	
VBE(sat)	Ic=3A, IB=0.6A	1.3max	V	
fT	Vce=12V, Ie=-0.5A	10typ	MHz	
Сов	VcB=10V, f=1MHz	50typ	pF	



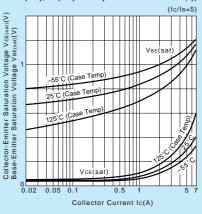
Typical Switching Characteristics (Common Emitter)

			•		,				
Vcc (V)	RL (Ω)	Ic (A)	V <sub>BB1</sub> (V)	VBB2 (V)	I <sub>B1</sub> (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
200	66	3	10	-5	0.3	-0.6	1max	3max	0.5max

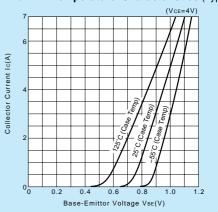




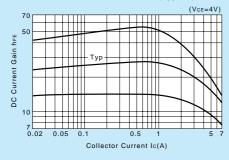
VcE(sat), VBE(sat)—Ic Temperature Characteristics (Typical)



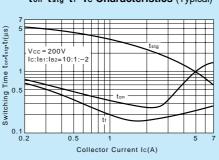
Ic-VBE Temperature Characteristics (Typical)



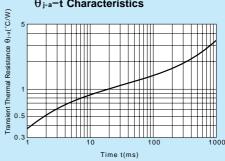
hfe-Ic Characteristics (Typical)



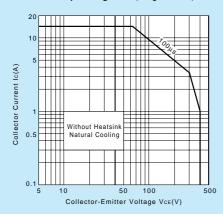
 $t_{\text{on}} \bullet t_{\text{stg}} \bullet t_{\text{f}} - I_{\text{C}} \text{ Characteristics (Typical)}$ 



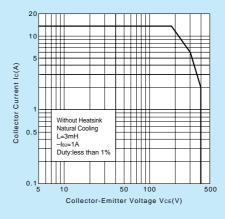
θ<sub>j-a</sub>-t Characteristics



Safe Operating Area (Single Pulse)



**Reverse Bias Safe Operating Area** 



Pc-Ta Derating

